

Textures of the polarisation field in ferroelectric nanowires from first principles



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Acknowledgments

Jiawang Hong (*Tsinghua U*)

D N Fang (*Tsinghua U*)

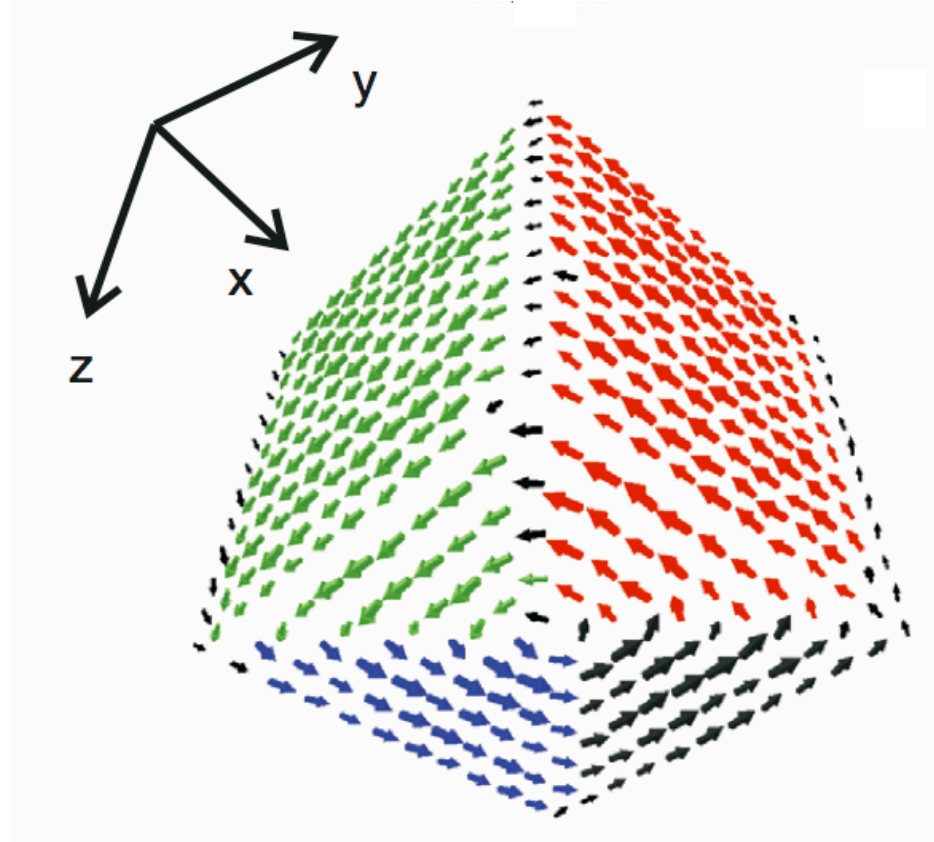
Gustau Catalan (*CIN2-CSIC Barcelona*)

Jim Scott (*U Cambridge*)



Ferroelectric nanostructures

Non-trivial topologies (vortices) proposed



Polarisation field $\mathbf{P}(\mathbf{r})$ found to be non-homogeneous in disks and rods of PZT (as simulated by local-mode model fitted from DFT)

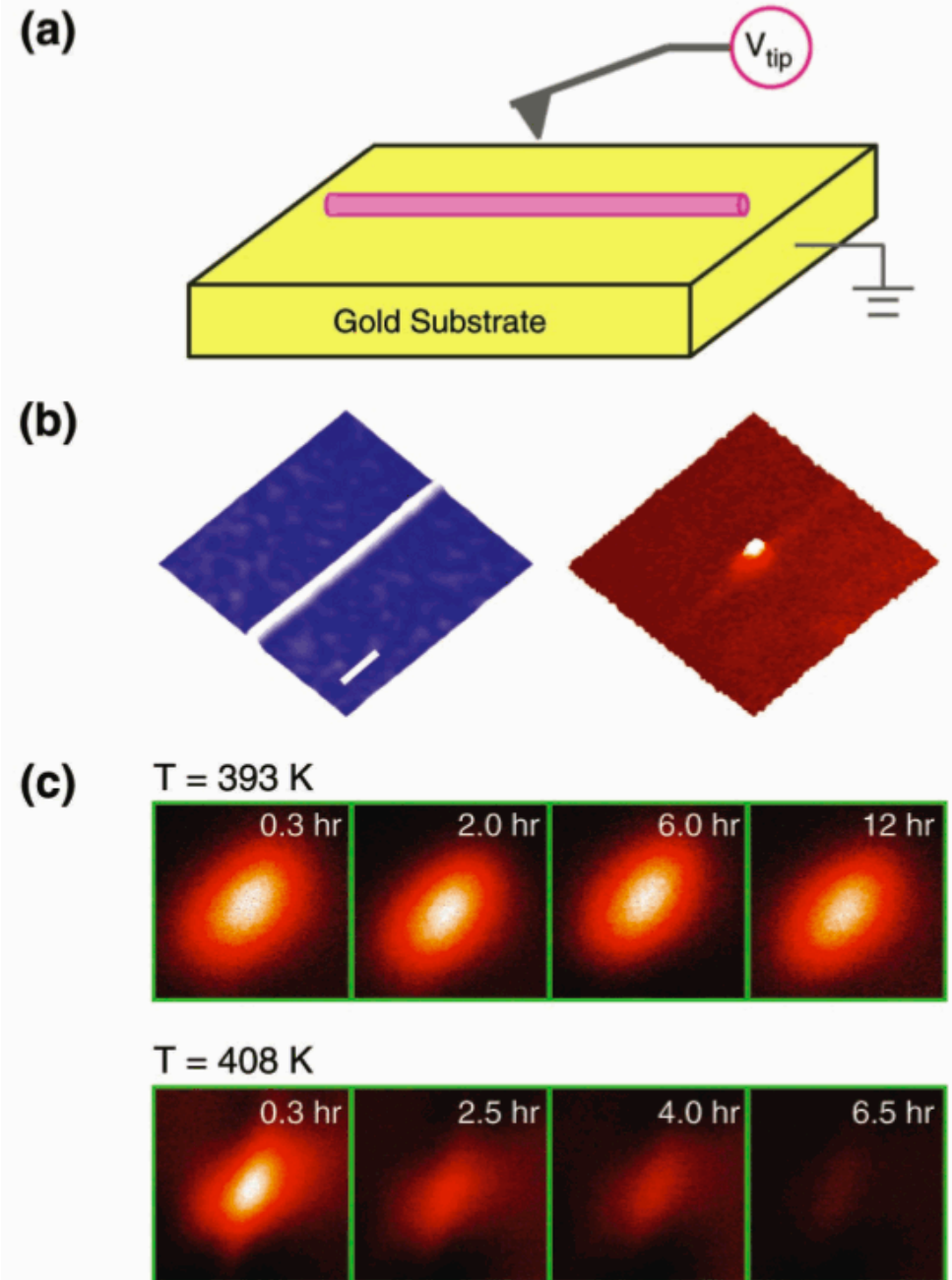
S Prosandeev et al, J. Phys.: Condens. Matter **20** (2008) 193201 (Review)

I Naumov, L Bellaiche & H Fu, Nature **432**, 737 (2004) , etc.

Ferroelectric nanowires Experiments

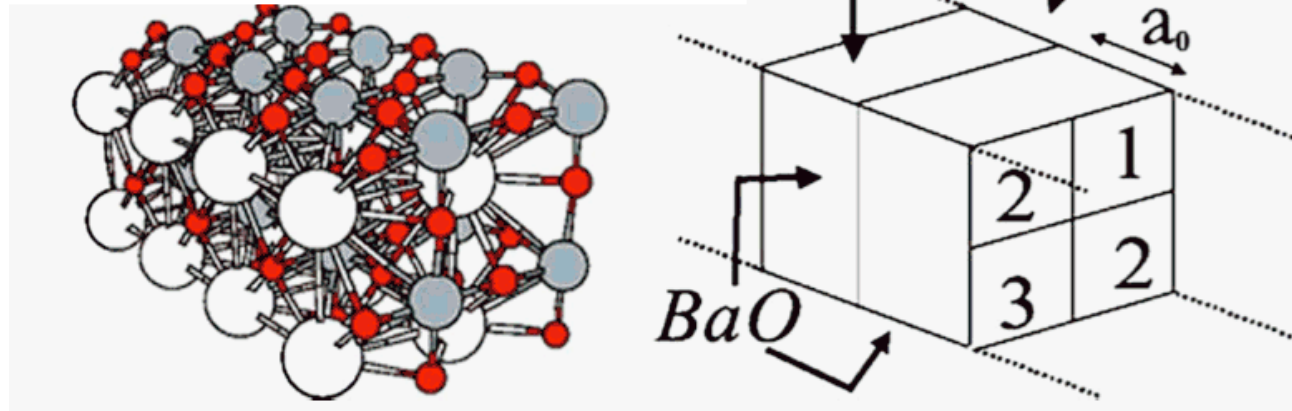
*Polarisation in BTO wires
of 3nm diameter*

J E Spanier et al,
Nano Lett. **6**, 735 (2006)



First-principles (DFT) simulations of thin wires

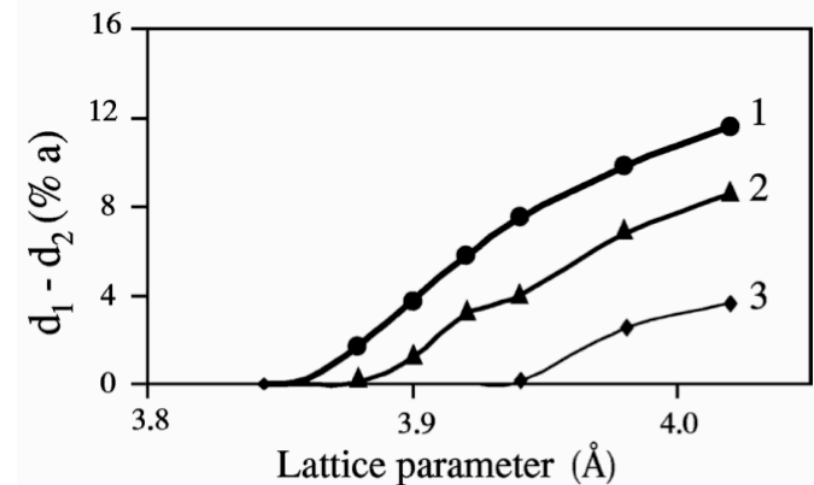
G. Geneste *et al*, Appl. Phys. Lett. **88**, 112906 (2006)



Polarisation field $\mathbf{P}(\mathbf{r})$ along z

Stoichiometric wires

Critical thickness (3x3)



The SIESTA method

Linear-scaling DFT based on Numerical Atomic Orbitals

P Ordejon, E Artacho & JM Soler , Phys. Rev. B 53, R10441 (1996)

- *Born-Oppenheimer* (relaxations, mol. dynamics)
- *DFT* (LDA, GGA)
- *Pseudopotentials* (norm conserving, factorised)
- *Numerical atomic orbitals as basis* (finite range)
- *Numerical evaluation of matrix elements* (3D grid)

Implemented in the SIESTA program

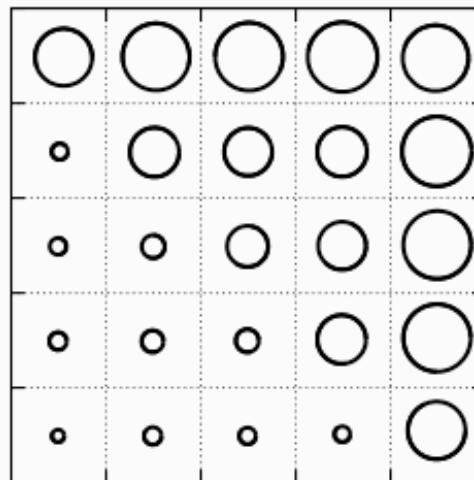
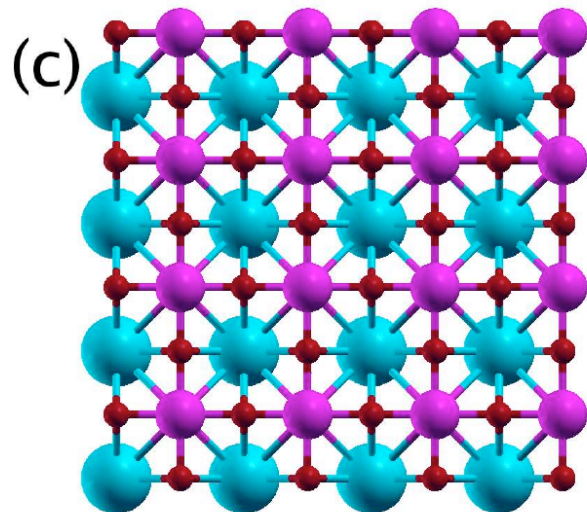
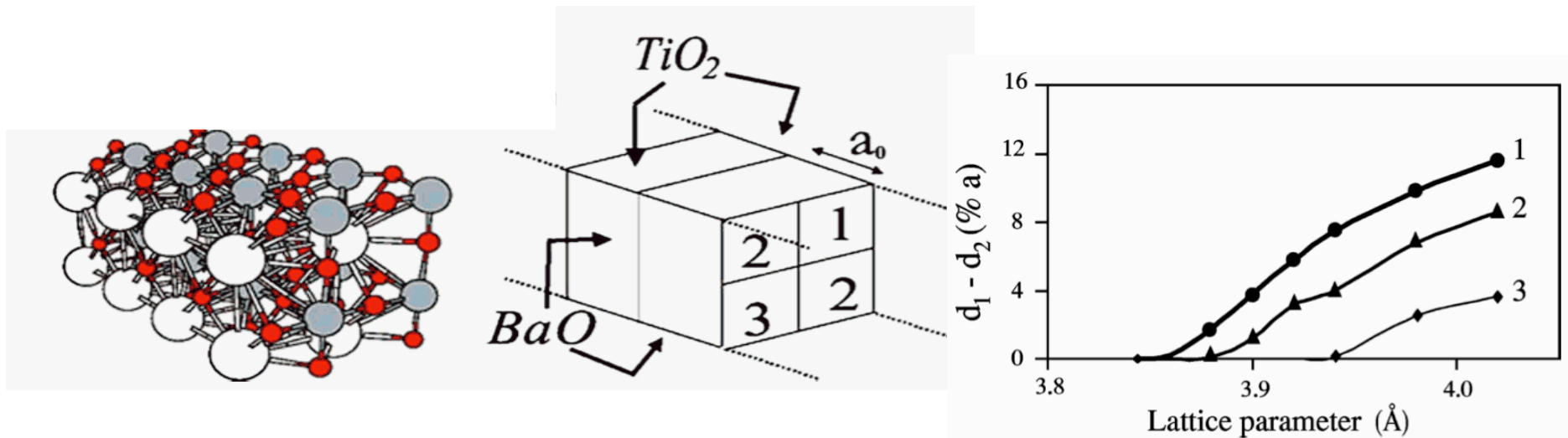
JM Soler, E Artacho, JD Gale, A Garcia, J Junquera, P Ordejon & D Sanchez-Portal,
J. Phys.: Condens. Matter **14**, 2745 (2002)

In this work: Structure relaxations from varied starting points

Ti off-centring used as proxy for Polarisation

Reproduced results of Geneste et al

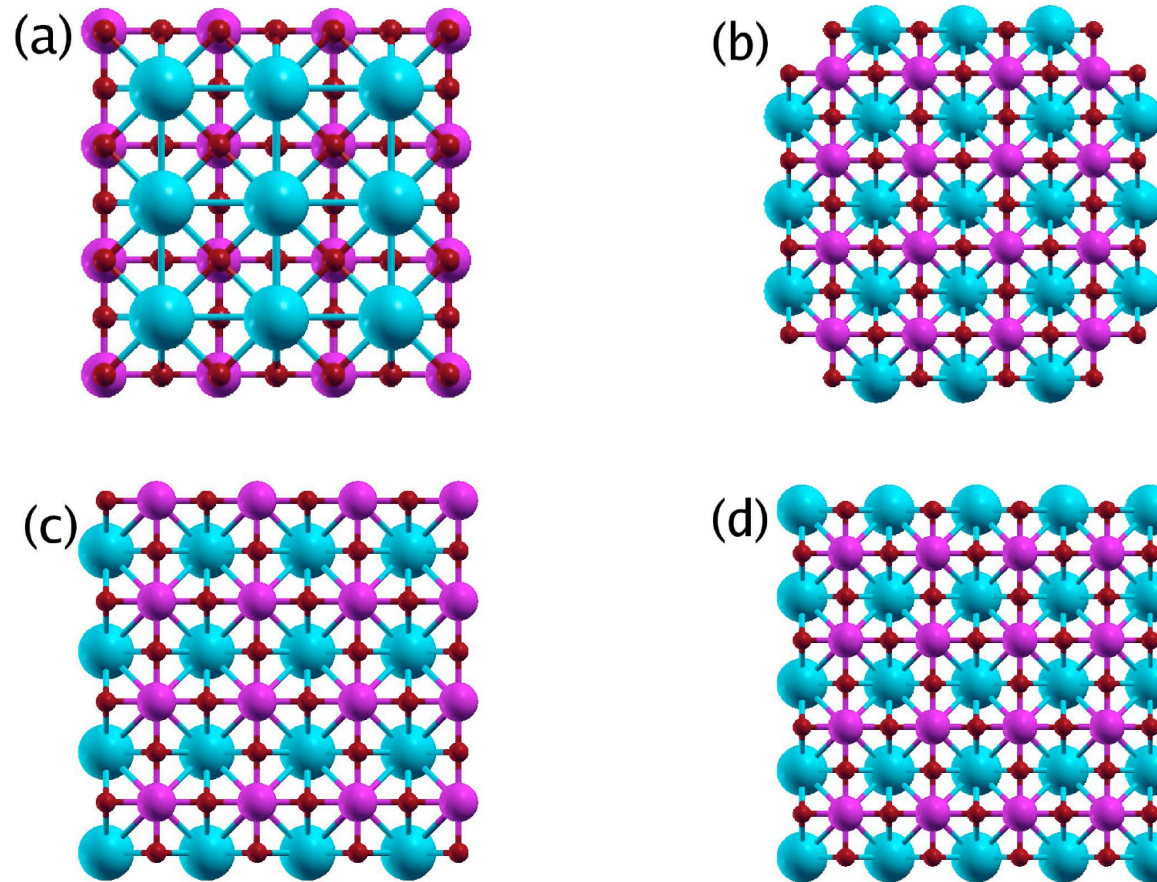
G. Geneste *et al*, Appl. Phys. Lett. **88**, 112906 (2006)



*Largest circle for 15 pm
(bulk BTO 13 pm)*

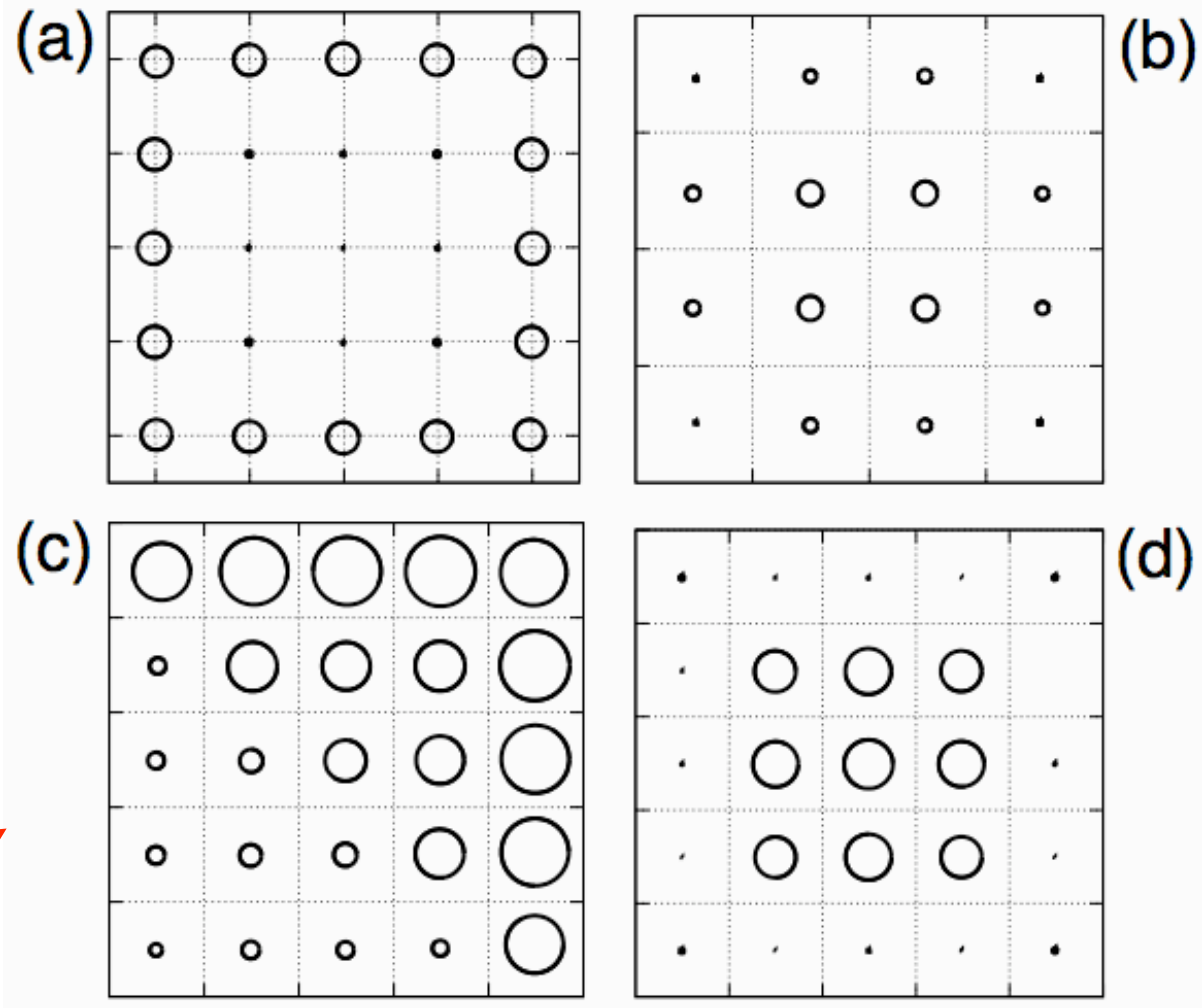
Topology of the polarization field in ferroelectric nanowires

JW Hong, G Catalan, DN Fang, E Artacho & JF Scott (arXiv 2009)



Basal section of the ferroelectric nanowires

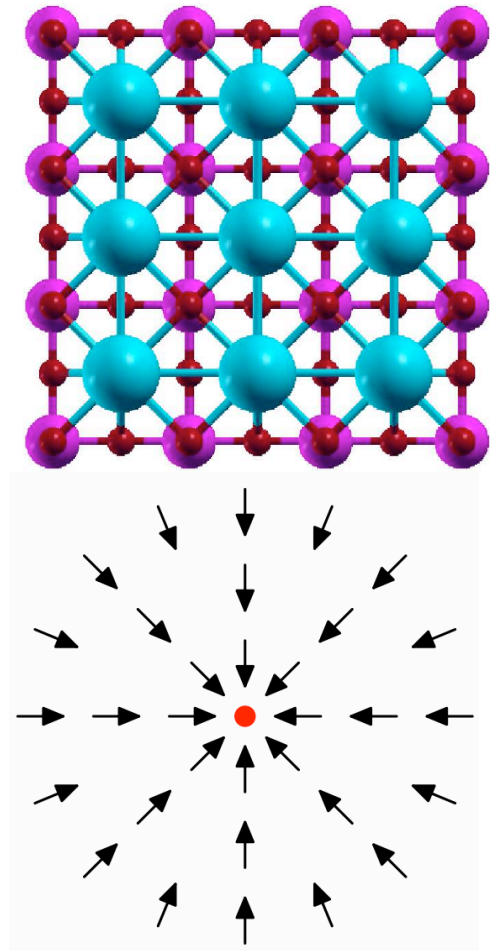
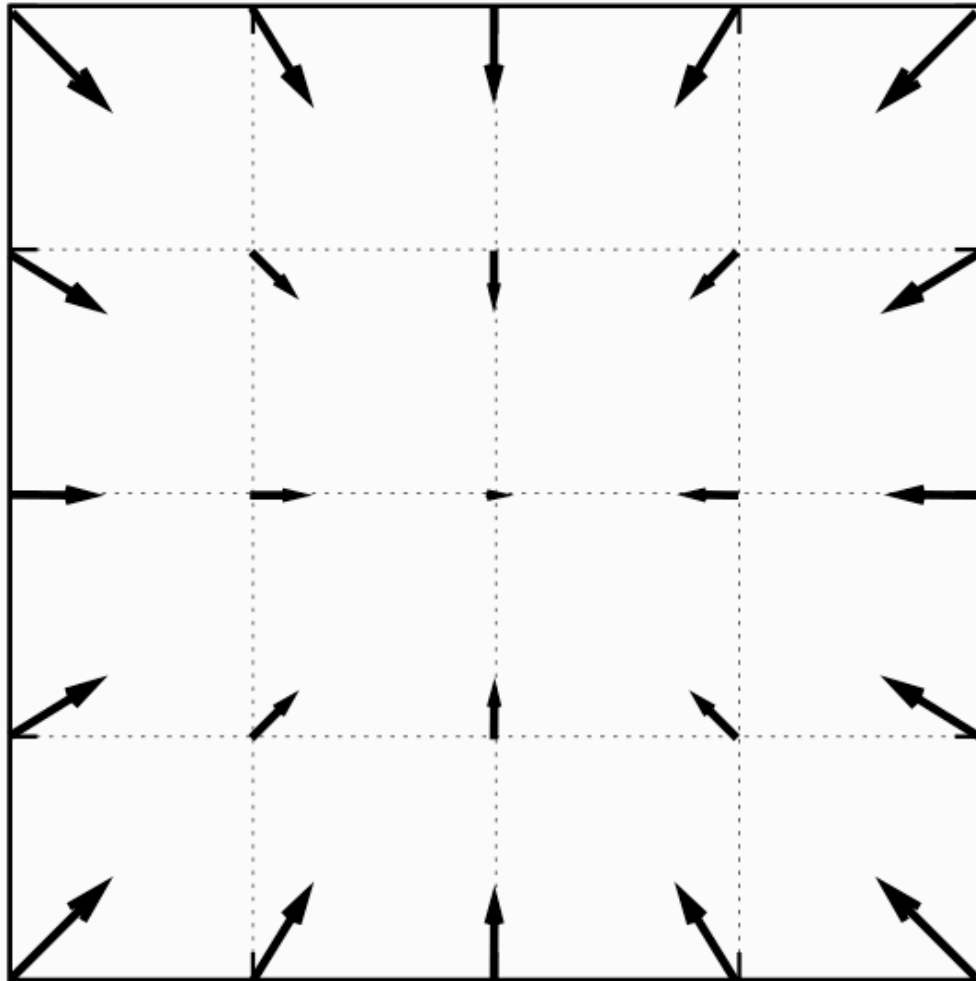
Polarisation along the wire axis (P_z)



The one shown before (stoichiometric)

Polarization field in the basal plane (P_x, P_y)

TiO₂ terminated



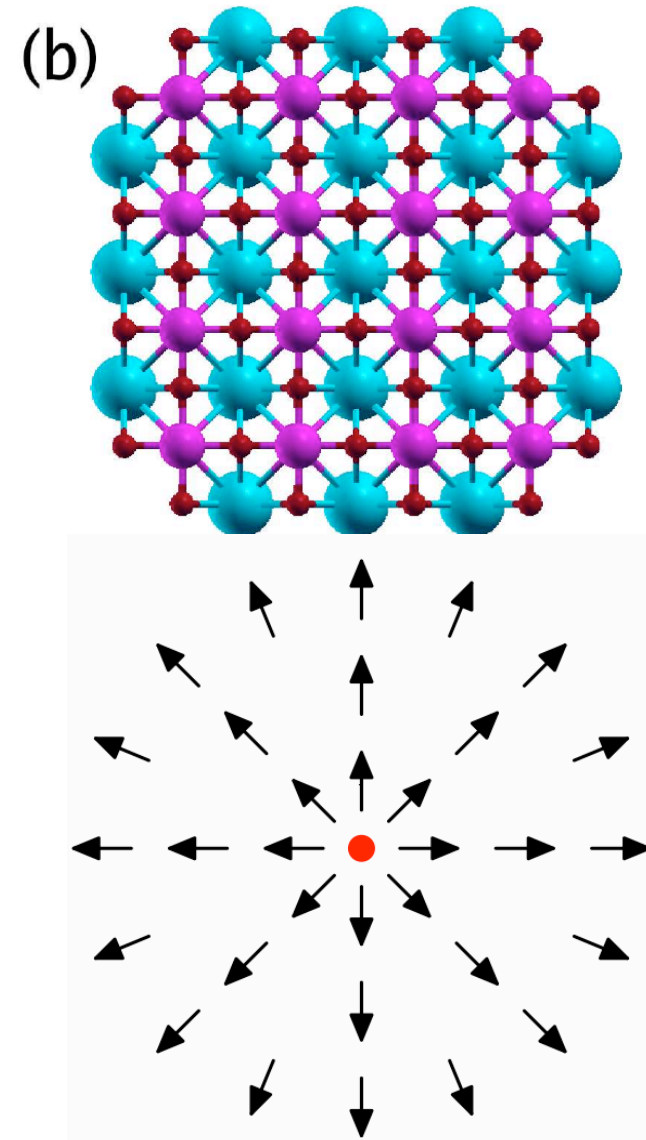
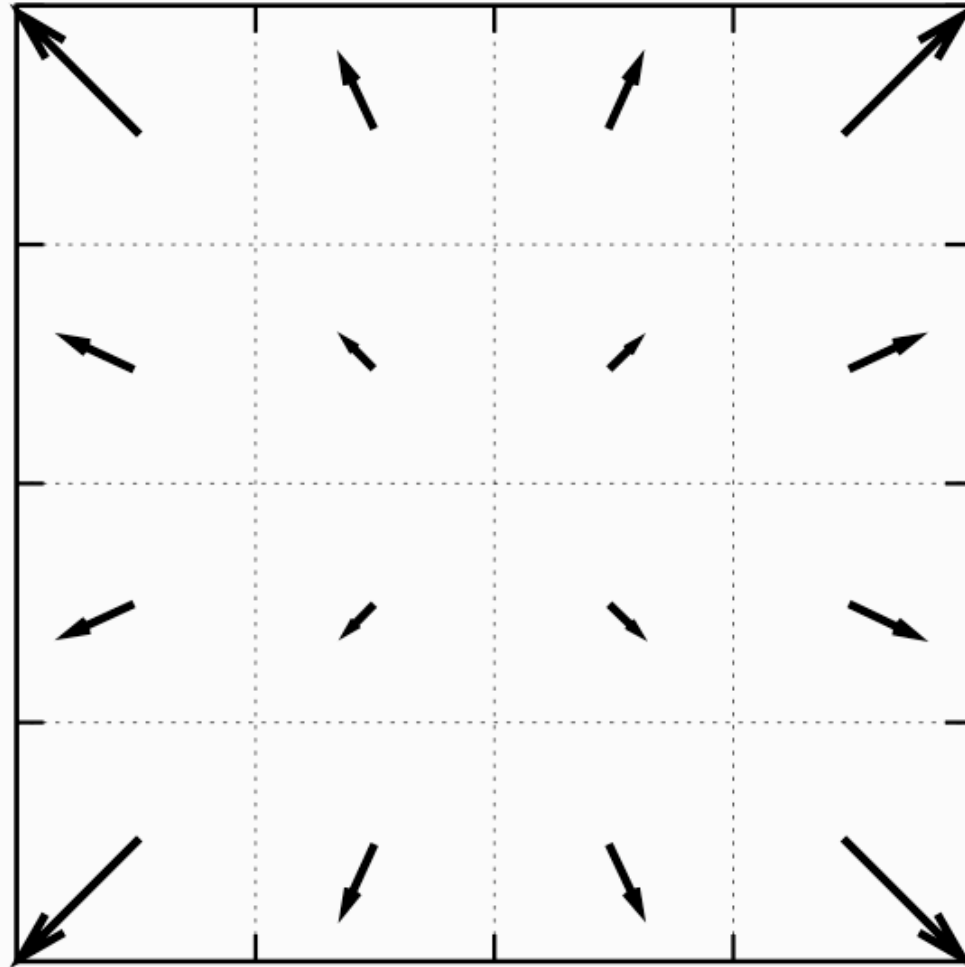
*Discretisation of
polarisation field*

*Surface & edge driven
(both push in here)*

(largest 21 pm)

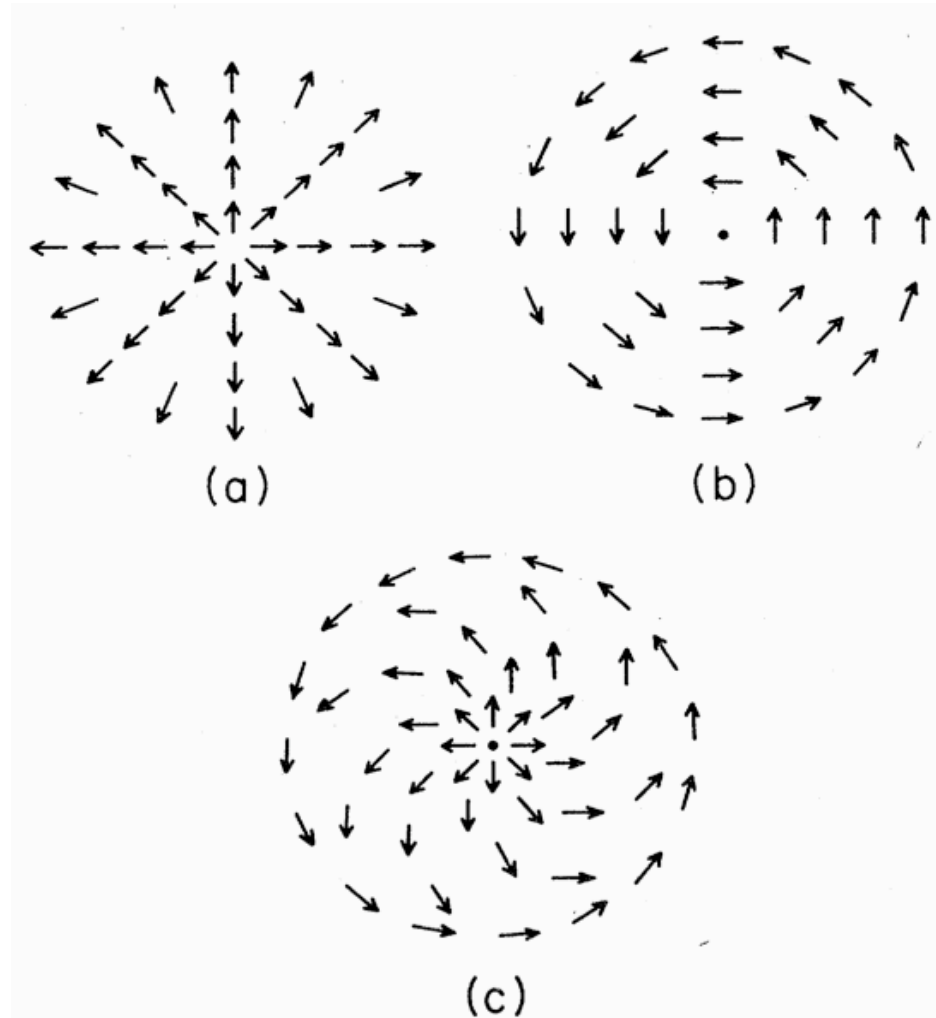
Different termination

BaO terminated removing corners



*Surface and edge pull out.
This and previous homotopical to vortex*

Smooth connection of homotopical textures



*Both previous and vortex, homotopical: Same topology
no disruption needed to transform from one to the other*

Topological defects

characterised by **winding number**

or **topological charge**

Number of times the field makes a full turn when going around in a closed circuit

For a continuum field, n is **integer**

(half-integer if non-directional field:
disclinations in liquid crystals)

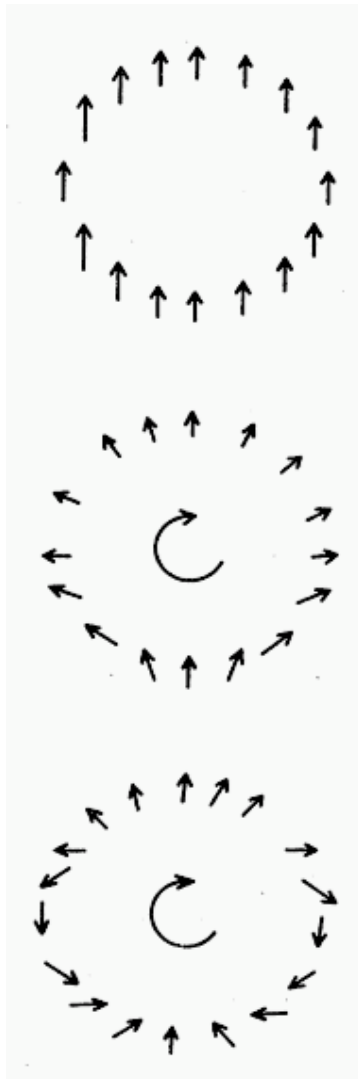
Sign: positive if field turns in same direction as circuit

They are **difficult to get rid of** (need general disruption)

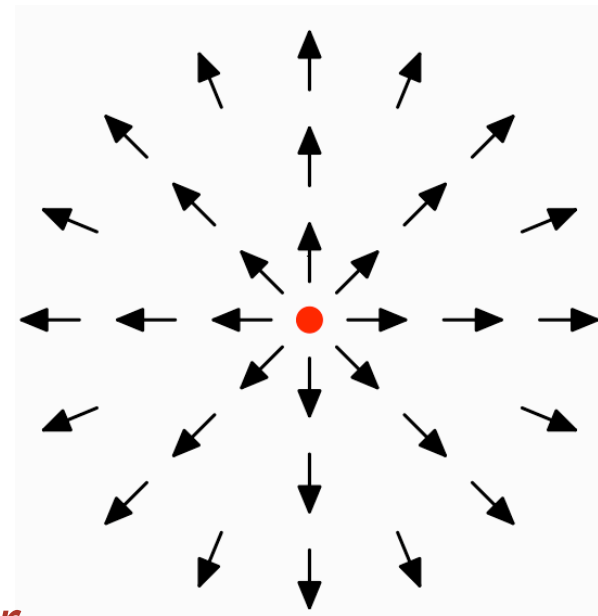
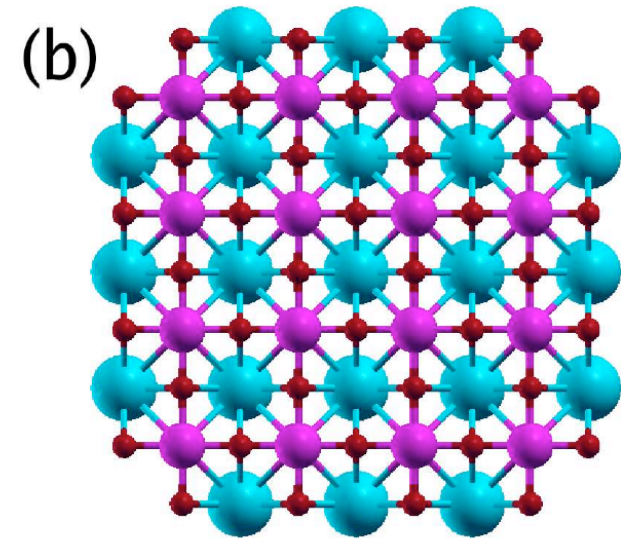
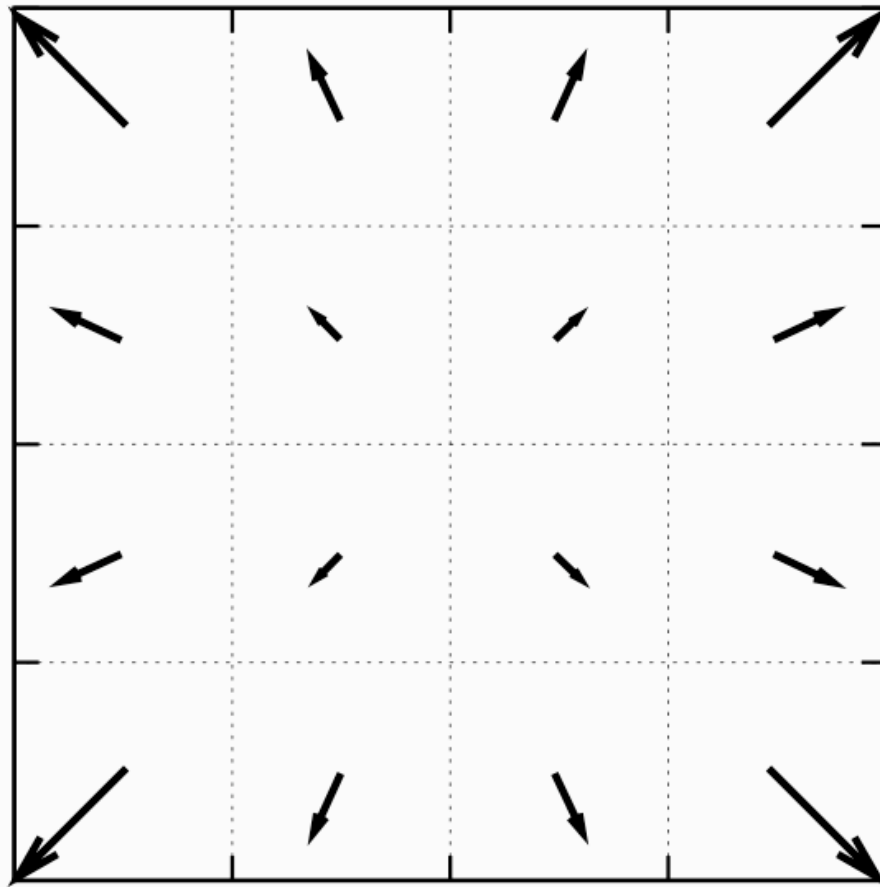
⇒ **Stable** (at least metastable)

(as solitons in 1D)

Naumov et al: nano phase transition

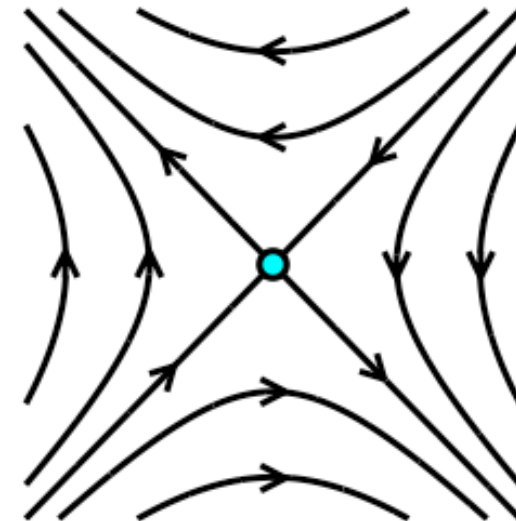
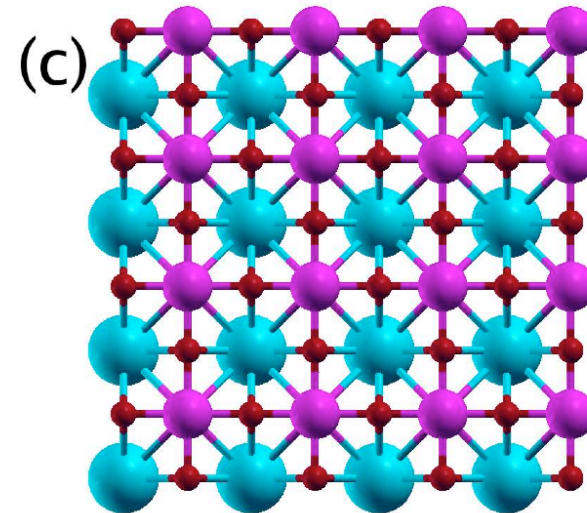
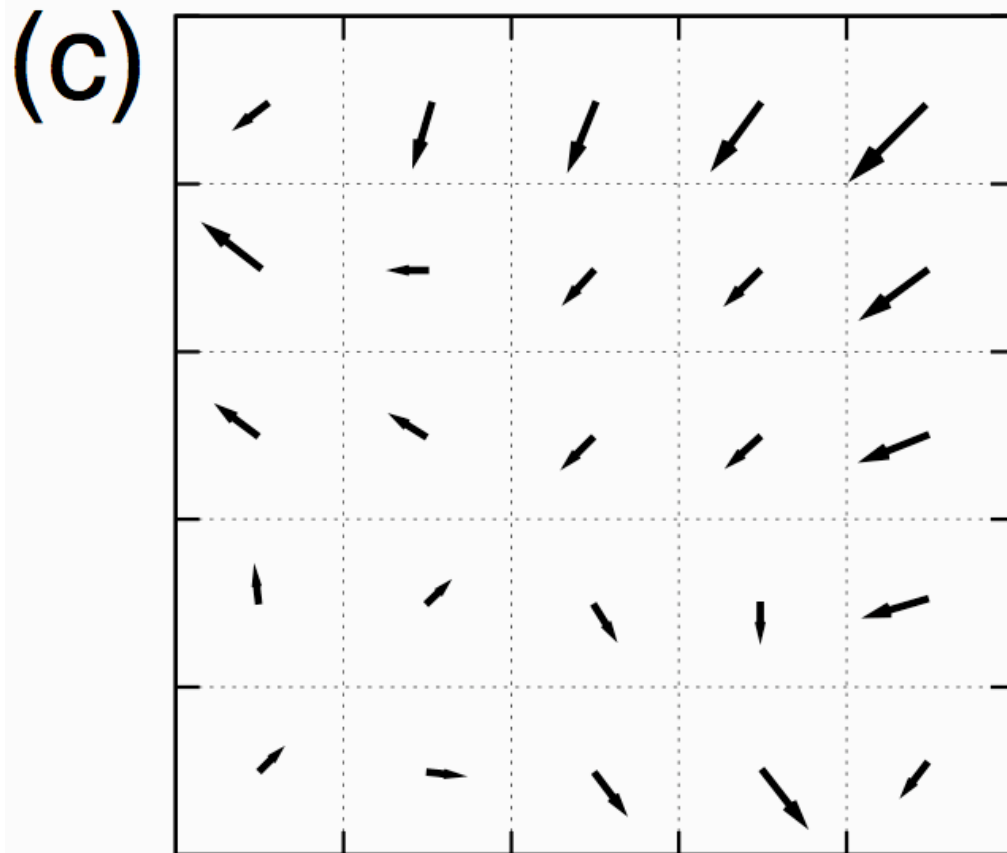


Back to radial pattern



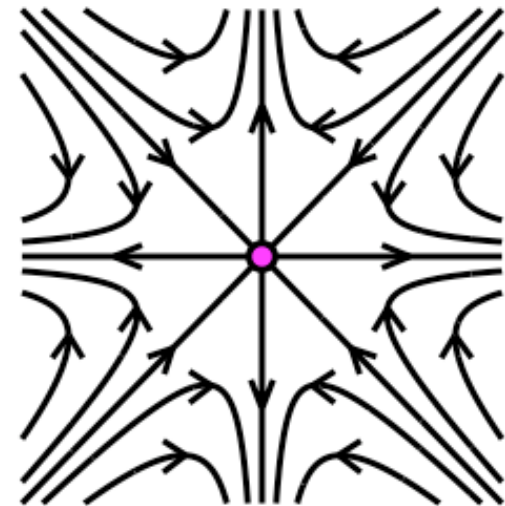
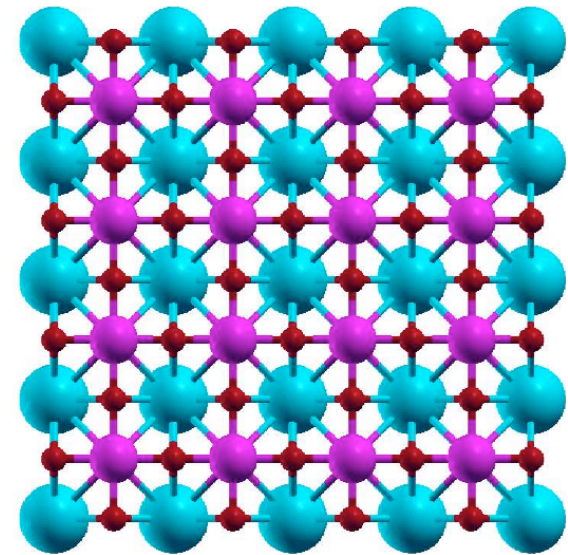
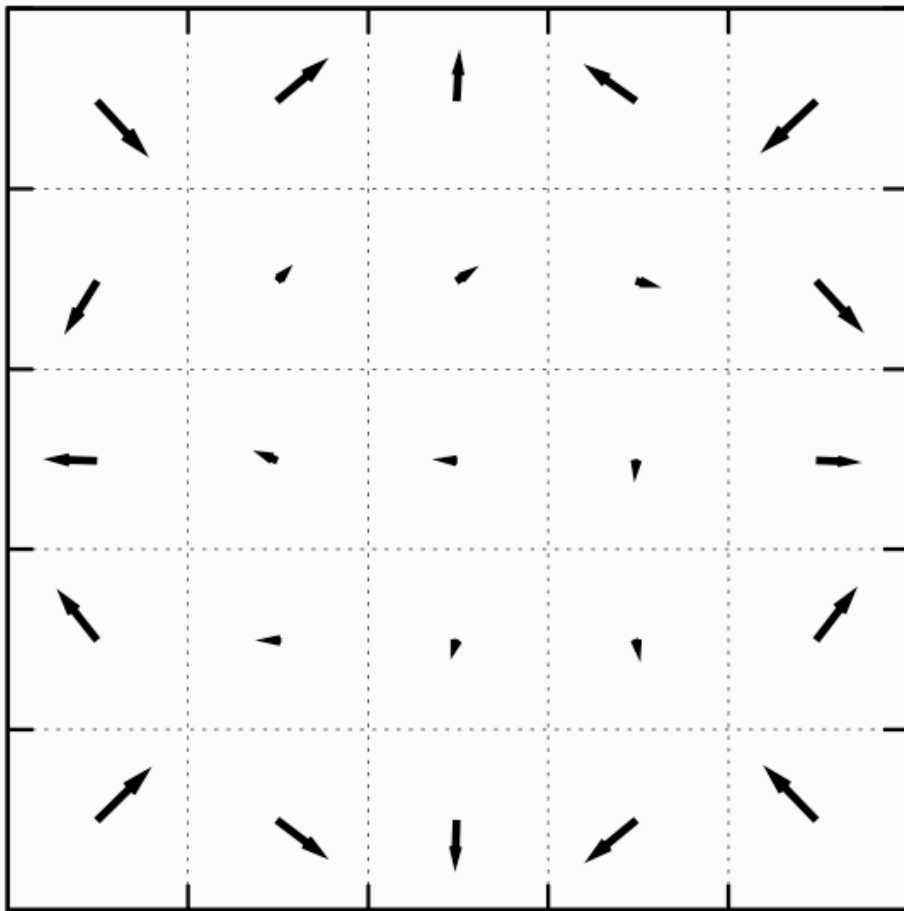
*Topological defect with winding number
 $n = +1$ (homotopical to vortex)*

*Change termination:
Stoichiometric wires*



Topological defect with winding number $n = -1$

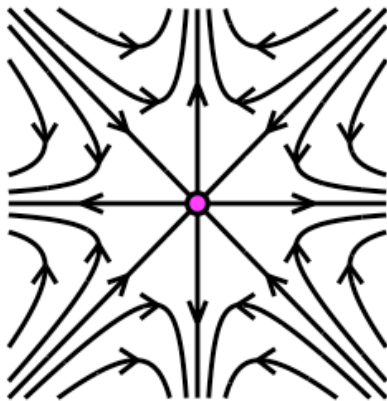
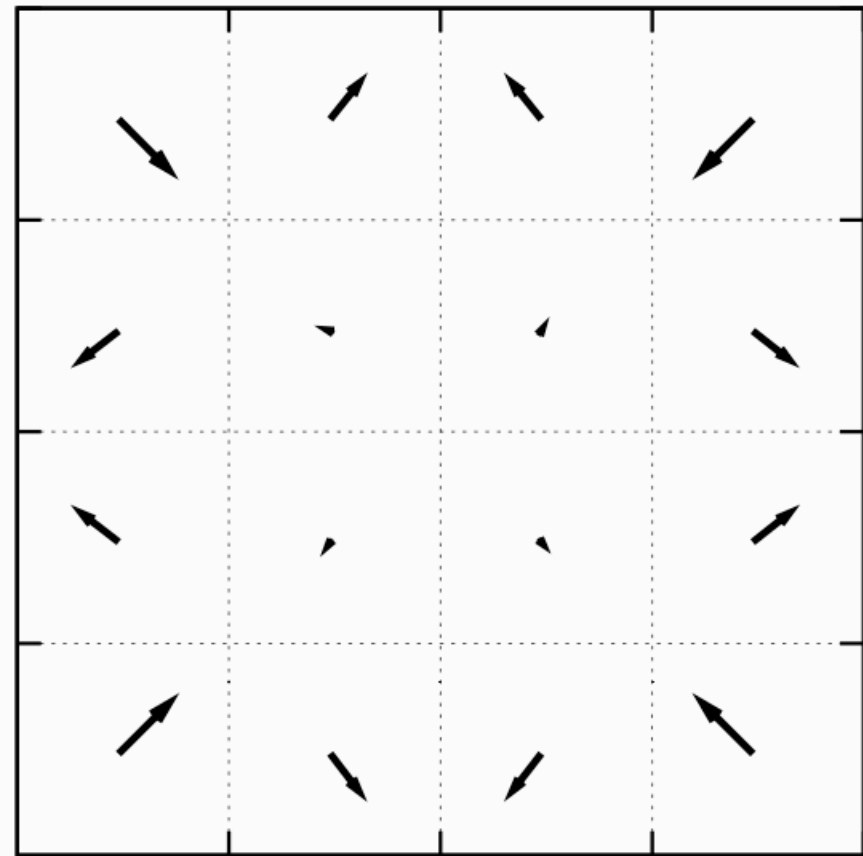
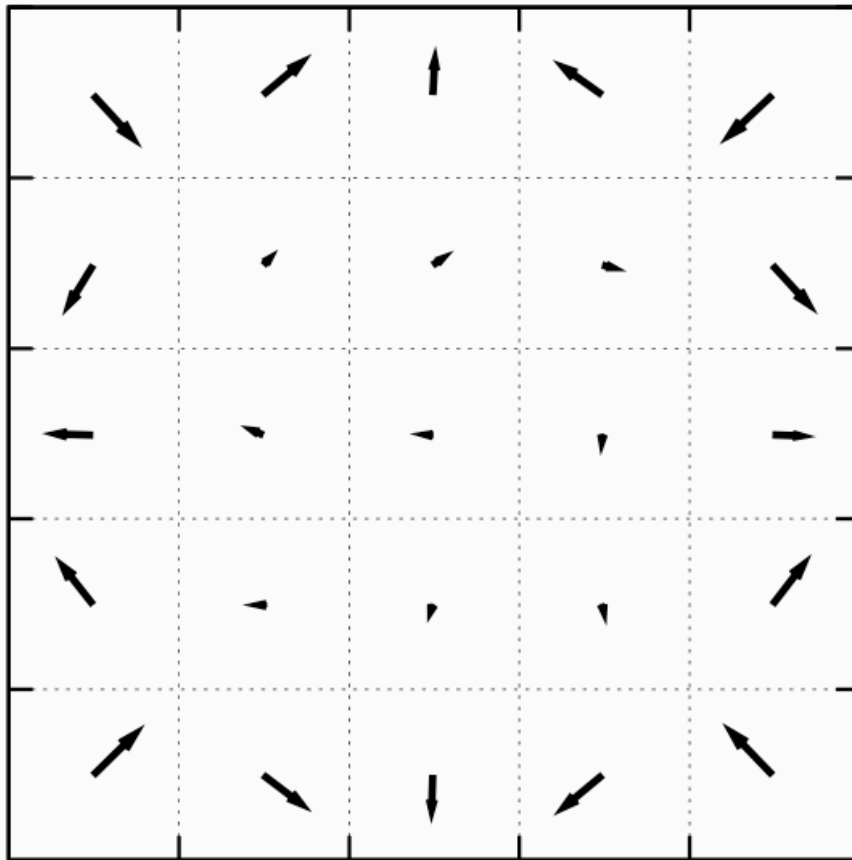
BaO terminated



Topological defect with winding number $n = -3$

Ba edge pushes, Ba surface pulls (largest 7 pm)

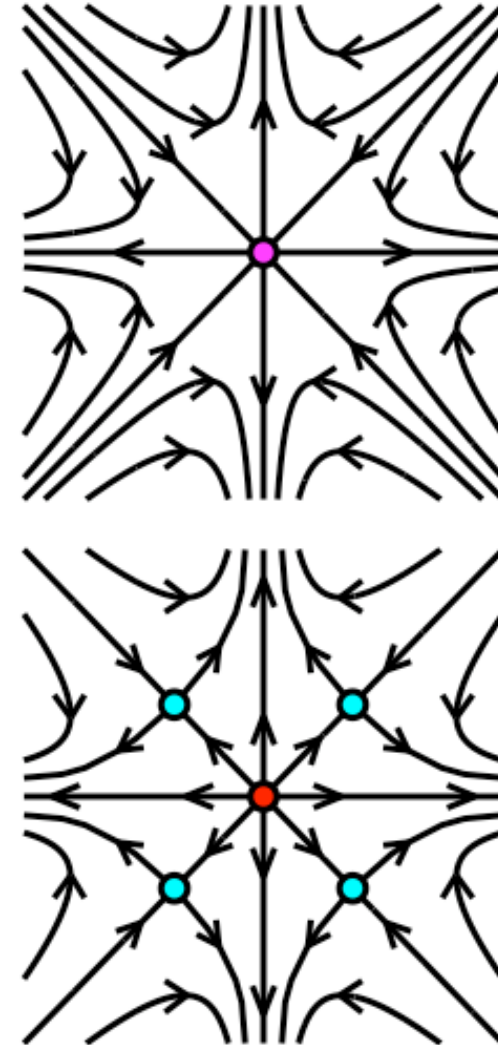
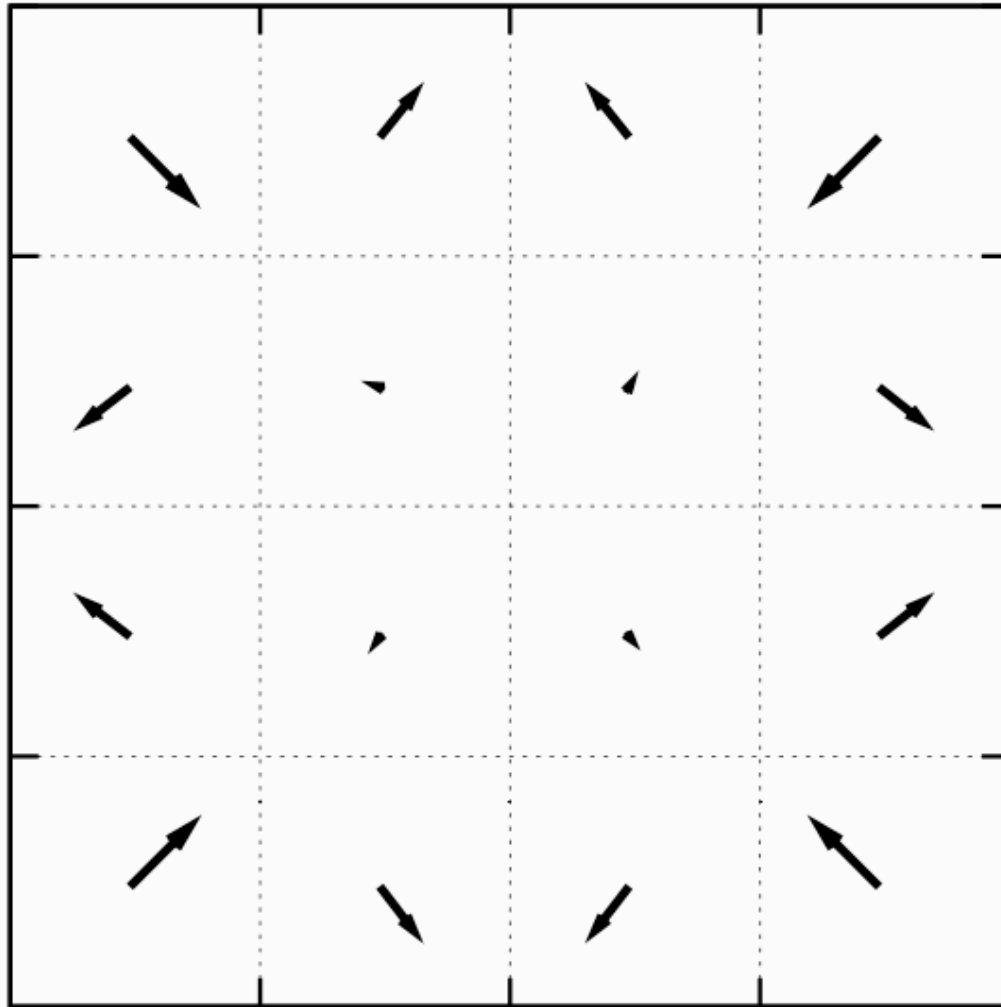
BaO terminated (different sizes)



- Both same outer-loop behaviour
- 5x5: no clear inner
- 4x4: inner: outwards (not $n=-3$)

BaO terminated (4x4)

Topological charge = Sum of charges of the topological point defects within



Topological defect with winding number $n = -3$

But now decomposed in 5 defects: $4 \times (n = -1) + 1 \times (n = +1)$

Back to the Ferroelectric nanowires Experiments

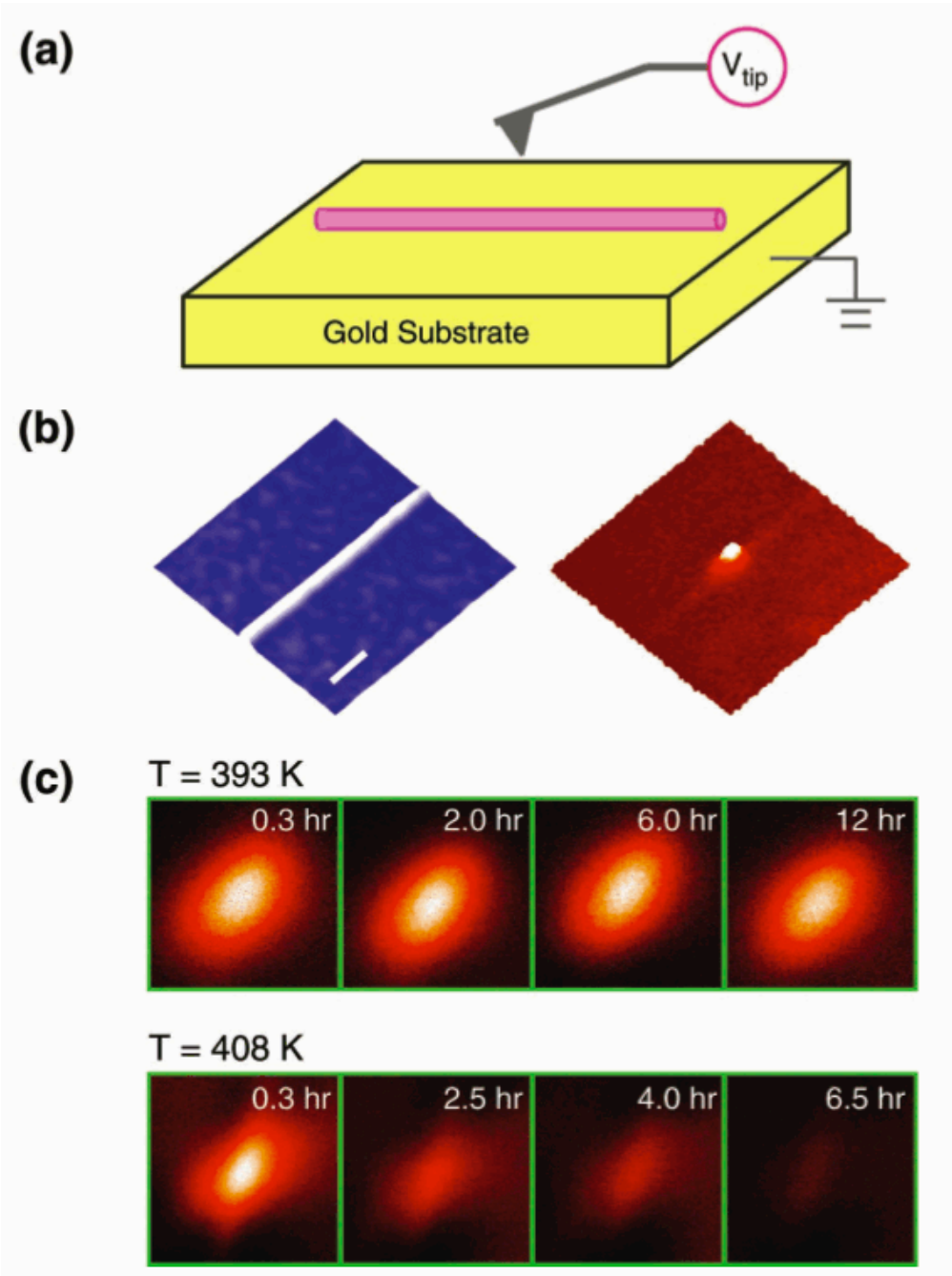
*Polarisation in BTO wires of
3nm diameter*

J E Spanier et al,
Nano Lett. **6**, 735 (2006)

*Transverse (homogeneous)
net polarization $\Rightarrow n = 0$*

*Ground state $n \neq 0$
 $P \sim 0$*

*Both states separate by
energy barrier*



Summary

- *Ferroelectric nanowires: topological defects*
- *Rich textures*
- *Experiments may be reflecting this*
- *Depend on surface chemistry*
- *Other terminations (e.g. hydroxylated) may be different again*
- *Possible base for ternary memory (-1, 0, +1)*